

# SSM3J353F

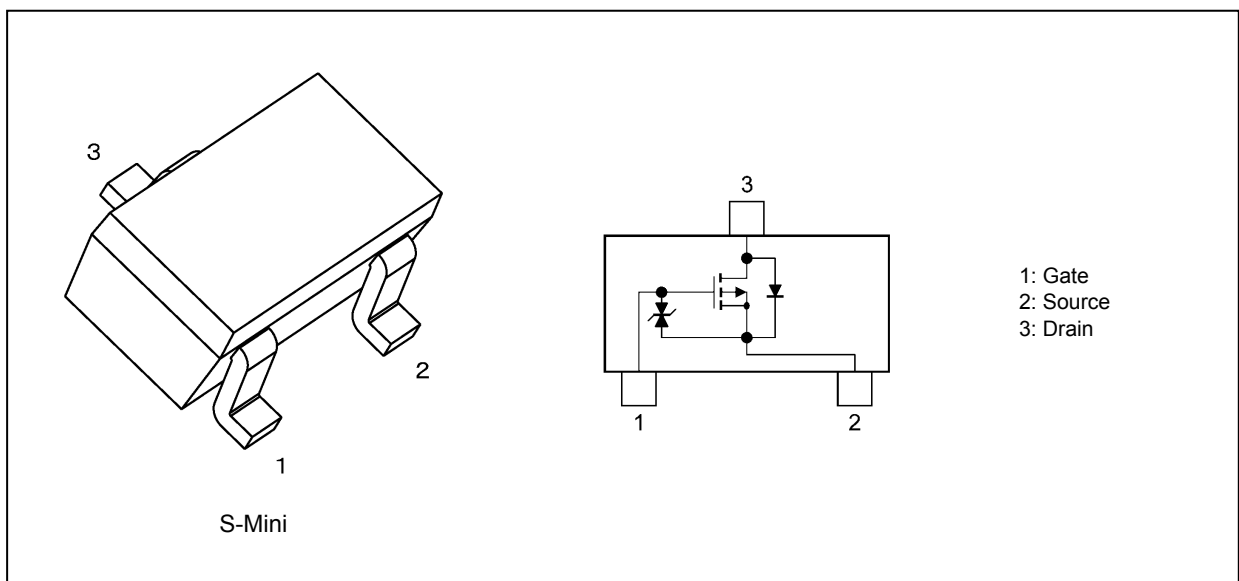
## 1. Applications

- Power Management Switches

## 2. Features

- (1) 4.0 V gate drive voltage.
- (2) Low drain-source on-resistance
  - :  $R_{DS(ON)} = 274 \text{ m}\Omega$  (max) (@ $V_{GS} = -4.0 \text{ V}$ ,  $I_D = -0.5 \text{ A}$ )
  - $R_{DS(ON)} = 232 \text{ m}\Omega$  (max) (@ $V_{GS} = -4.5 \text{ V}$ ,  $I_D = -0.5 \text{ A}$ )
  - $R_{DS(ON)} = 150 \text{ m}\Omega$  (max) (@ $V_{GS} = -10 \text{ V}$ ,  $I_D = -2.0 \text{ A}$ )

## 3. Packaging and Pin Assignment



Start of commercial production

2016-02

**4. Absolute Maximum Ratings (Note) (Unless otherwise specified,  $T_a = 25\text{ }^\circ\text{C}$ )**

Characteristics	Symbol	Rating	Unit
Drain-source voltage	$V_{DSS}$	-30	V
Gate-source voltage	$V_{GSS}$	-25 / +20	
Drain current (DC) (Note 1)	$I_D$	-2.0	A
Drain current (pulsed) (Note 1), (Note 2)	$I_{DP}$	-4.0	
Power dissipation (Note 3)	$P_D$	600	mW
Power dissipation $t \leq 1\text{ s}$ (Note 3)		1200	
Channel temperature	$T_{ch}$	150	$^\circ\text{C}$
Storage temperature	$T_{stg}$	-55 to 150	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Ensure that the channel temperature does not exceed  $150\text{ }^\circ\text{C}$ .

Note 2: Repetitive rating; pulse width limited by maximum channel temperature.

Note 3: Device mounted on a  $25.4\text{ mm} \times 25.4\text{ mm} \times 1.6\text{ mm}$  FR4 glass epoxy board (Cu pad:  $645\text{ mm}^2$ )

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

Note: The MOSFETs in this device are sensitive to electrostatic discharge. When handling this device, the worktables, operators, soldering irons and other objects should be protected against anti-static discharge.

Note: The channel-to-ambient thermal resistance,  $R_{th(ch-a)}$ , and the drain power dissipation,  $P_D$ , vary according to the board material, board area, board thickness and pad area. When using this device, be sure to take heat dissipation fully into account.

**5. Electrical Characteristics**

**5.1. Static Characteristics (Unless otherwise specified,  $T_a = 25\text{ }^\circ\text{C}$ )**

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current	$I_{GSS}$	$V_{GS} = \pm 16\text{ V}$	—	—	$\pm 1$	$\mu\text{A}$
Drain cut-off current	$I_{DSS}$	$V_{DS} = -30\text{ V}, V_{GS} = 0\text{ V}$	—	—	-1	
Drain-source breakdown voltage	$V_{(BR)DSS}$	$I_D = -1\text{ mA}, V_{GS} = 0\text{ V}$	-30	—	—	V
Drain-source breakdown voltage (Note 1)	$V_{(BR)DSX}$	$I_D = -1\text{ mA}, V_{GS} = 8\text{ V}$	-22	—	—	
Gate threshold voltage	$V_{th}$	$V_{DS} = V_{GS}, I_D = -0.25\text{ mA}$	-1.0	—	-2.2	
Drain-source on-resistance (Note 2)	$R_{DS(ON)}$	$I_D = -0.5\text{ A}, V_{GS} = -4.0\text{ V}$	—	198	274	$\text{m}\Omega$
		$I_D = -0.5\text{ A}, V_{GS} = -4.5\text{ V}$	—	176	232	
		$I_D = -2.0\text{ A}, V_{GS} = -10\text{ V}$	—	125	150	
Forward transfer admittance (Note 2)	$ Y_{fs} $	$V_{DS} = -10\text{ V}, I_D = -1.0\text{ A}$	—	2.6	—	S

Note 1: If a reverse bias is applied between gate and source, this device enters  $V_{(BR)DSX}$  mode. Note that the drain-source breakdown voltage is lowered in this mode.

Note 2: Pulse measurement.

**5.2. Dynamic Characteristics (Unless otherwise specified,  $T_a = 25\text{ }^\circ\text{C}$ )**

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Input capacitance	$C_{iss}$	$V_{DS} = -15\text{ V}, V_{GS} = 0\text{ V},$ $f = 1\text{ MHz}$	—	159	—	$\text{pF}$
Reverse transfer capacitance	$C_{rss}$		—	23	—	
Output capacitance	$C_{oss}$		—	30	—	
Switching time (turn-on time)	$t_{on}$	$V_{DS} = -15\text{ V}, I_D = -1.0\text{ A},$ $V_{GS} = 0\text{ to }-4.5\text{ V}, R_G = 15\text{ }\Omega$	—	30	—	ns
Switching time (turn-off time)	$t_{off}$		—	34	—	

**5.3. Switching Time Test Circuit**

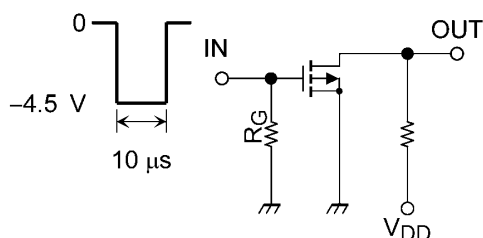


Fig. 5.3.1 Switching Time Test Circuit

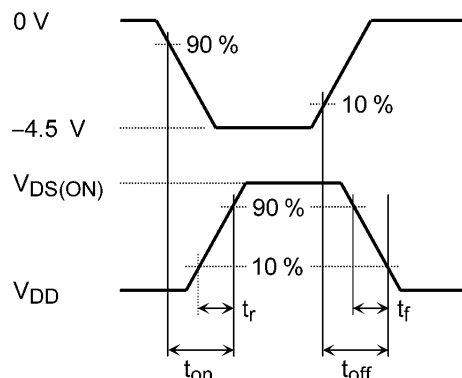


Fig. 5.3.2 Input Waveform/Output Waveform

**5.4. Gate Charge Characteristics (Unless otherwise specified,  $T_a = 25\text{ }^\circ\text{C}$ )**

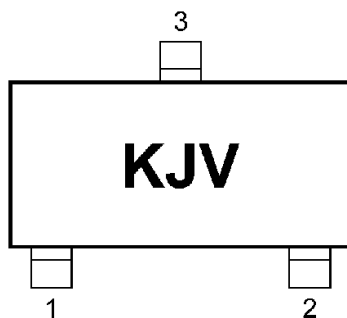
Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Total gate charge (gate-source plus gate-drain)	$Q_g$	$V_{DD} = -15\text{ V}, I_D = -2.0\text{ A},$ $V_{GS} = -4.5\text{ V}$	—	3.4	—	nC
Gate-source charge 1	$Q_{gs1}$		—	1.5	—	
Gate-drain charge	$Q_{gd}$		—	1.4	—	

**5.5. Source-Drain Characteristics (Unless otherwise specified,  $T_a = 25\text{ }^\circ\text{C}$ )**

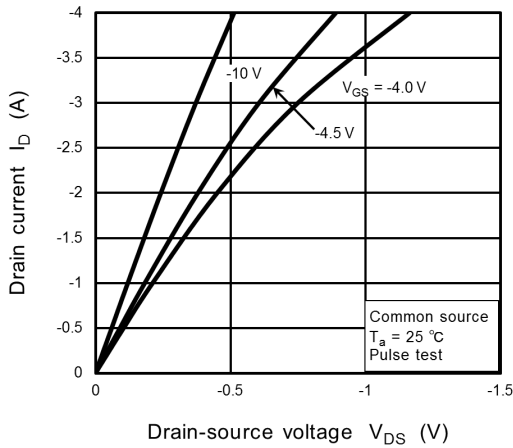
Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Diode forward voltage (Note 1)	$V_{DSF}$	$I_D = 2.0\text{ A}, V_{GS} = 0\text{ V}$	—	0.9	1.2	V

Note 1: Pulse measurement.

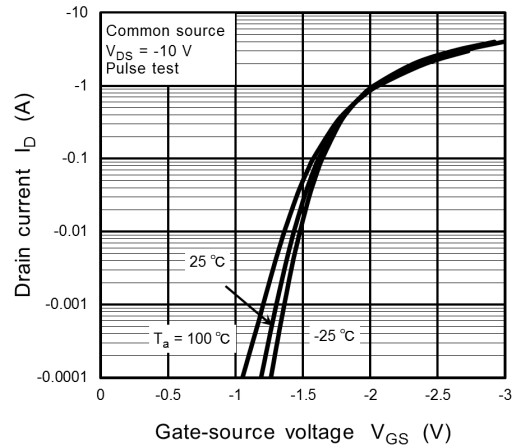
6. Marking



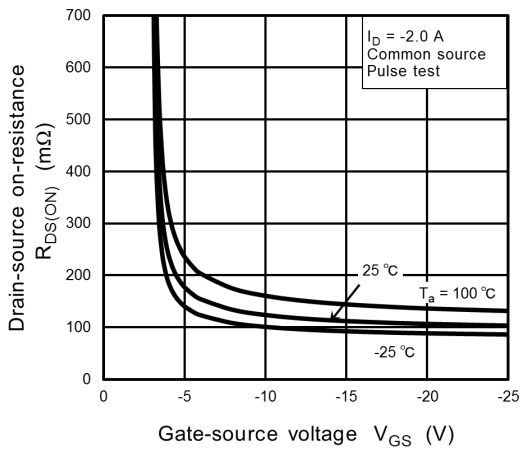
**7. Characteristics Curves (Note)**



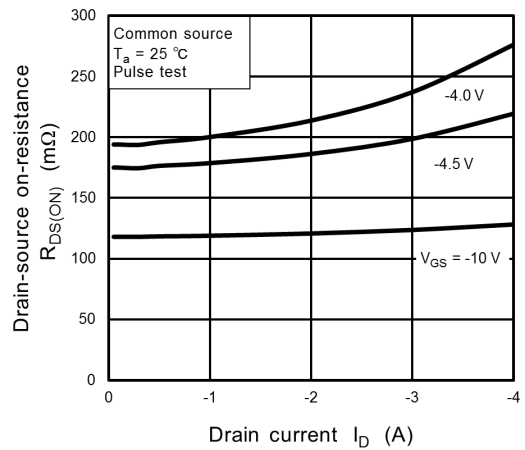
**Fig. 7.1  $I_D - V_{DS}$**



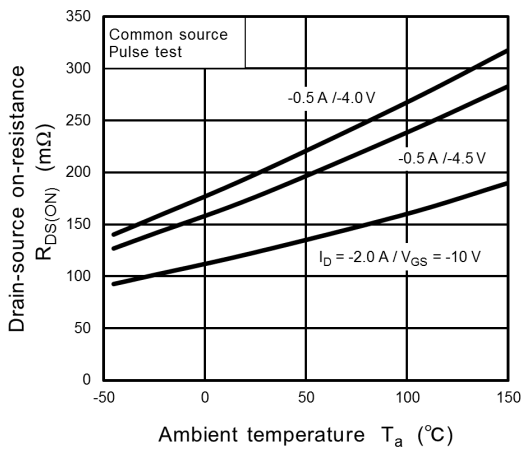
**Fig. 7.2  $I_D - V_{GS}$**



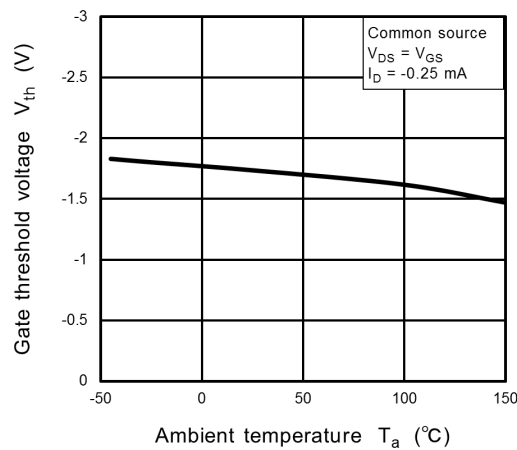
**Fig. 7.3  $R_{DS(ON)} - V_{GS}$**



**Fig. 7.4  $R_{DS(ON)} - I_D$**



**Fig. 7.5  $R_{DS(ON)} - T_a$**



**Fig. 7.6  $V_{th} - T_a$**

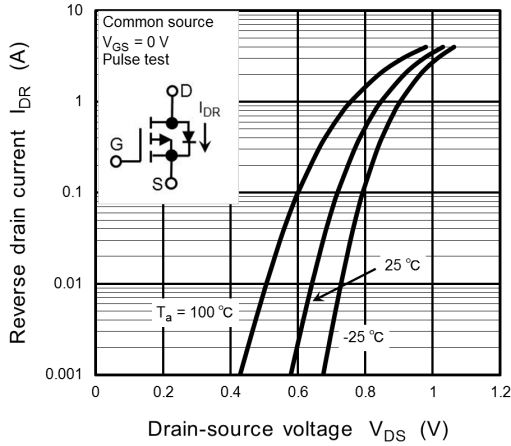


Fig. 7.7  $I_{DR} - V_{DS}$

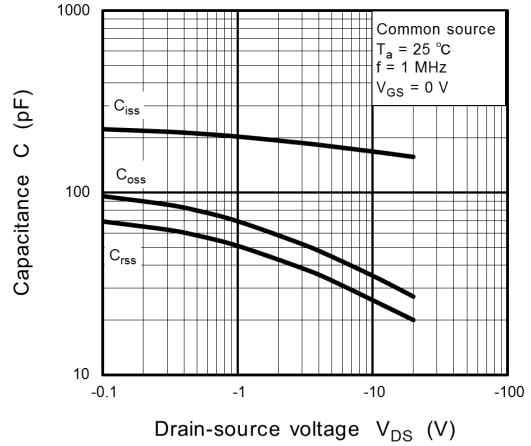


Fig. 7.8  $C - V_{DS}$

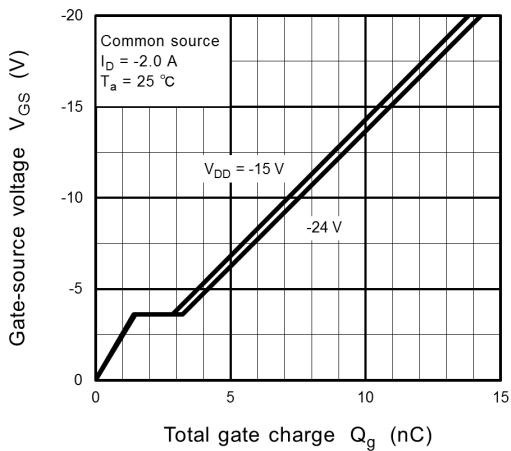


Fig. 7.9 Dynamic Input Characteristics

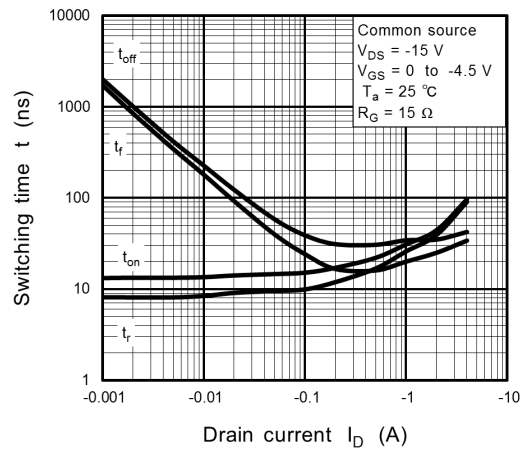


Fig. 7.10  $t - I_D$

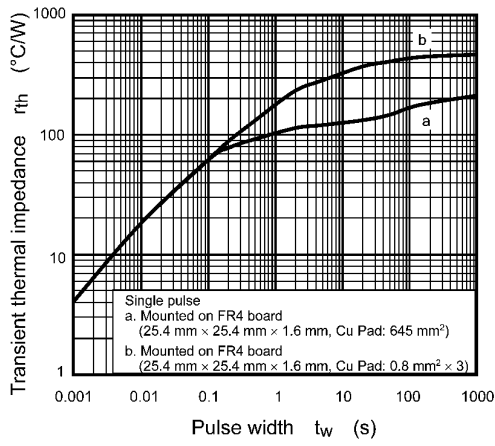


Fig. 7.11  $r_{th} - t_w$

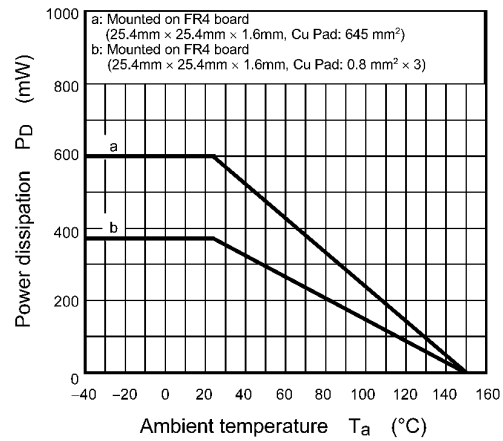
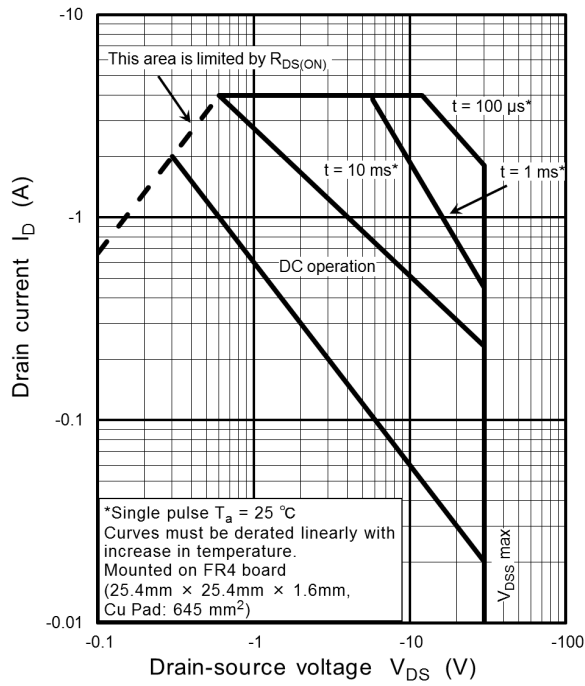


Fig. 7.12  $P_D - T_a$

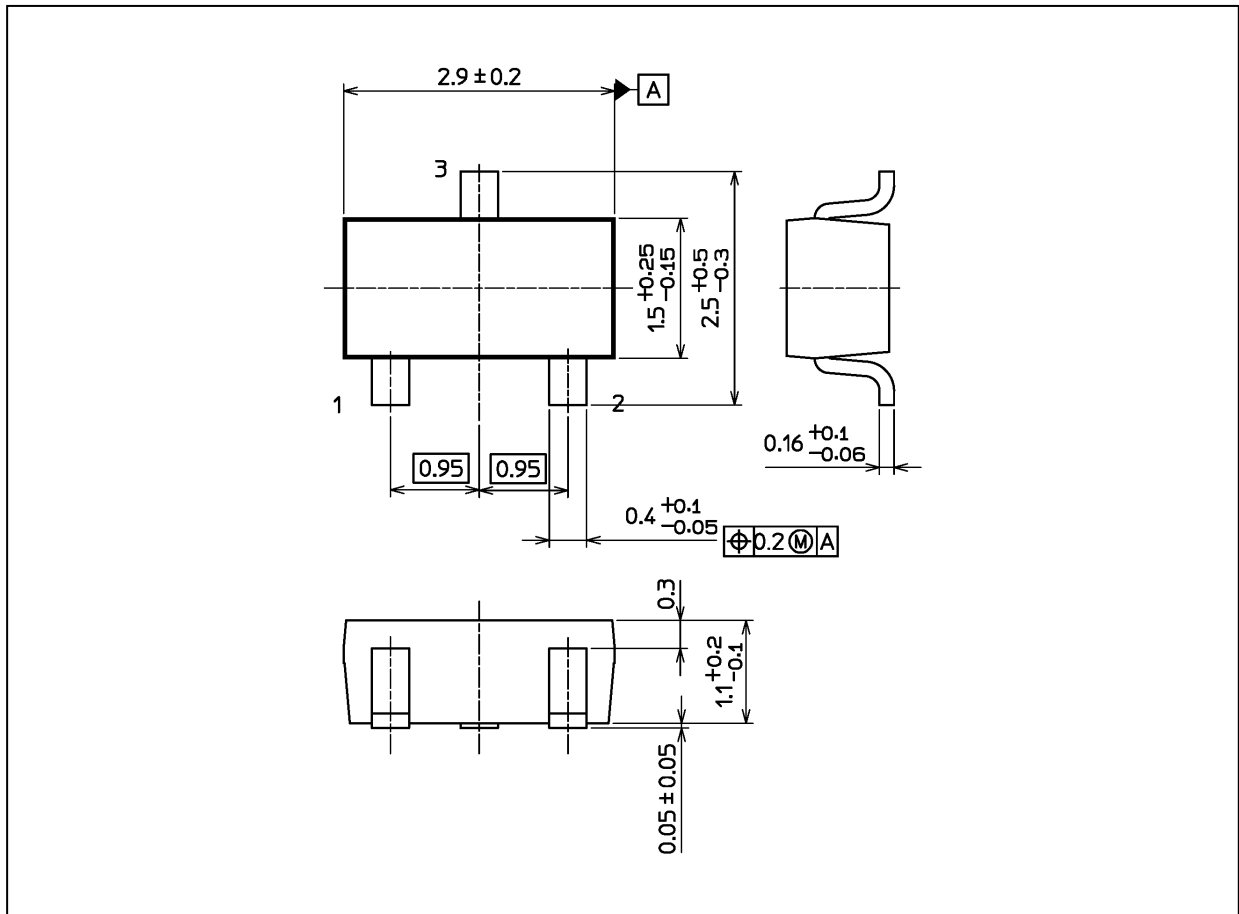


**Fig. 7.13 Safe Operating Area**

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

Package Dimensions

Unit: mm



Weight: 12 mg (typ.)

Package Name(s)
Nickname: S-Mini



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